



### **Description:**

Designed for general-purpose amplifier and low speed switching applications.

- Collector-Emitter sustaining voltage-V $_{\rm CEO~(sus)}$  = 60V (Min.) TIP140 Collector-Emitter saturation voltage-V $_{\rm CE~(sat)}$  = 2.5V (Max.) at I $_{\rm C}$  = 5A
- Monolithic construction with built-in-base-emitter shunt resistor

### **Maximum Ratings**

Characteristic	Symbol	Values	Unit	
Collector-Emitter Voltage	V <sub>CEO</sub>	60		
Collector-Base Voltage	V <sub>CBO</sub>	60	V	
Emitter-Base Voltage	V <sub>EBO</sub>	5		
Collector Current-Continuous -Peak	I <sub>C</sub>	10 15 A		
Base Current	I <sub>B</sub>	0.5		
Total Power Dissipation at T <sub>C</sub> = 25°C Derate above 25°C	P <sub>D</sub>	125 1	W W/°C	
Operation and Storage Junction Temperature Range	T <sub>J</sub> , T <sub>STG</sub>	-65 to +150	°C	

### **Thermal Characteristics**

Characteristic	Symbol	Max.	Unit
Thermal Resistance Junction to Case	$R_{\theta jc}$	1	°C/W





## Electrical Characteristics (T<sub>C</sub> = 25°C unless otherwise noted)

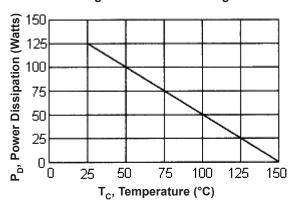
	• •				
Ch	aracteristic	Symbol	Min.	Max.	Unit
Off Characteristics		•			•
Collector-Emitter Sustaining I <sub>C</sub> = 30mA, I <sub>B</sub> = 0	Voltage (1)	V <sub>CEO (sus)</sub>	60	-	V
Collector Cut off Current $V_{CE} = 30V$ , $I_{B} = 0$		I <sub>CEO</sub>	-	2	
Collector Cut off Current $V_{CB} = 60V$ , $I_{E} = 0$		I <sub>CBO</sub>	-	1	mA
Emitter Cut off Current $V_{EB} = 5V$ , $I_{C} = 0$		I <sub>EBO</sub>	-	2	
On Characteristics (1)					
DC Current Gain $I_C = 5A$ , $V_{CE} = 4V$ $I_C = 10A$ , $V_{CE} = 40V$		h <sub>FE</sub>	1,000 500	-	-
Collector-Emitter Saturation Voltage $I_C = 5A$ , $I_B = 10mA$ $I_C = 10A$ , $I_B = 40mA$		V <sub>CE (sat)</sub>	-	2	
Base-Emitter Saturation Voltage $I_C = 10A$ , $I_B = 40mA$ Base-Emitter On Voltage $I_C = 10A$ , $V_{CE} = 4V$		V <sub>BE (sat)</sub>		3.5	V
		V <sub>BE (on)</sub>	-	3.0	
Switching Characteristics					
Delay Time	$V_{CC} = 30V, I_{C} = 5A$ $I_{B1} = -I_{B2} = 20mA$ $t_{D} = 20ms, Duty Cycle £2%$	t <sub>d</sub>	0.15 (Typ.)	-	
Rise Time		t <sub>r</sub>	0.55 (Typ.)	-	116
Storage Time		t <sub>s</sub>	2.5 (Typ.)	-	μs
Fall Time		t <sub>f</sub>	2.5 (Typ.)	-	

<sup>(1)</sup> Pulse Test: Pulse Width =  $300\mu s$ , Duty Cycle  $\leq 2\%$ .

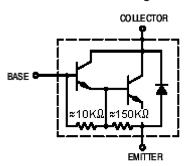


# multicomp PRO

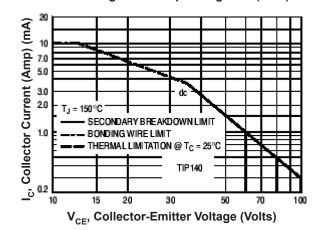
Figure - 1 Power Derating



**Internal Schematic Diagram** 



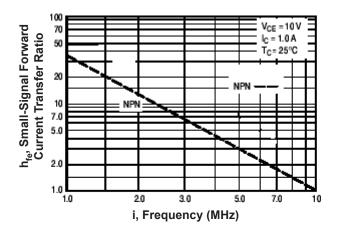
**Active Region Safe Operating Area (SOA)** 



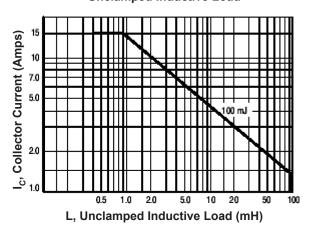
There are two limitation on the power handling ability of a transistor: average junction temperature and second breakdown safe operating area curves indicate  $I_{\rm C}\text{-V}_{\rm CE}$  limits of the transistor that must be observed for reliable operation i.e., the transistor must not be subjected to greater dissipation than curves indicate.

The data of SOA curve is based on  $T_{J\ (PK)}$  = 150°C;  $T_{C}$  is variable depending on conditions. At high case temperatures, thermal limitation will reduce the power that can be handled to values less than the limitations imposed by second breakdown.

Small-Signal Common-Emitter Forward Current Transfer Ratio

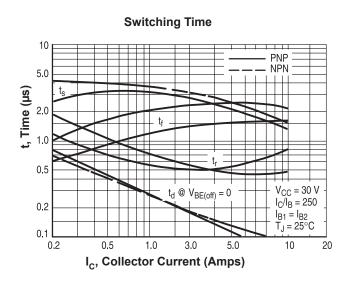


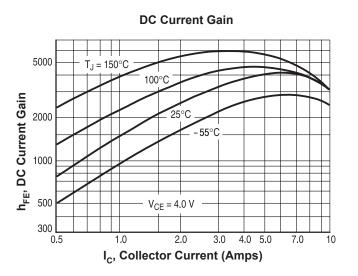
**Unclamped Inductive Load** 



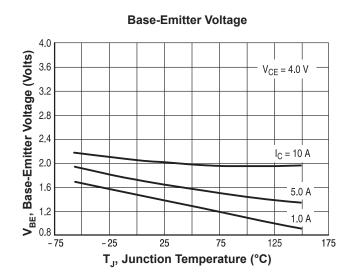






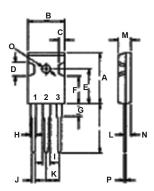


# Collector-Emitter Saturation Voltage 5.0 3.0 3.0 1<sub>C</sub> = 10 A, I<sub>B</sub> = 4.0 mA 1<sub>C</sub> = 5.0 A, I<sub>B</sub> = 10 mA 1<sub>C</sub> = 1.0 A, I<sub>B</sub> = 2.0 mA









### Pin Configuration:

- 1. Base
- 2. Collector
- 3. Emitter

Dimensions	Min.	Max.
Α	20.63	22.38
В	15.38	16.2
С	1.9	2.7
D	5.1	6.1
E	14.81	15.22
F	11.72	12.84
G	4.2	4.5
Н	1.82	2.46
I	2.92	3.23
J	0.89	1.53
K	5.26	5.66
L	18.5	21.5
M	4.68	5.36
N	2.4	2.8
0	3.25	3.65
Р	0.55	0.7

Dimensions: Millimetres

### **Part Number Table**

Description	Part Number
Darlington Transistor, NPN, TO-247	TIP140

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